NSN 5961-00-415-1971

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View Online at https://aerobasegroup.com/nsn/5961-00-415-1971 **Inclosure Material:** Metal **Overall Length:** 1.231 inches **End Application:** Aircraft, prowler ea-6b; velocity pool reparable piece parts. **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-111 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -5.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** Between -1.00 amperes source cutoff current and -5.00 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts collector power dissipation outside diameter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp; weapon system essential **Thread Series Designator:** Unf **Terminal Type And Quantity:**

Shelf Life: N/a

Unit Of Measure:

3 tab, solder lug

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